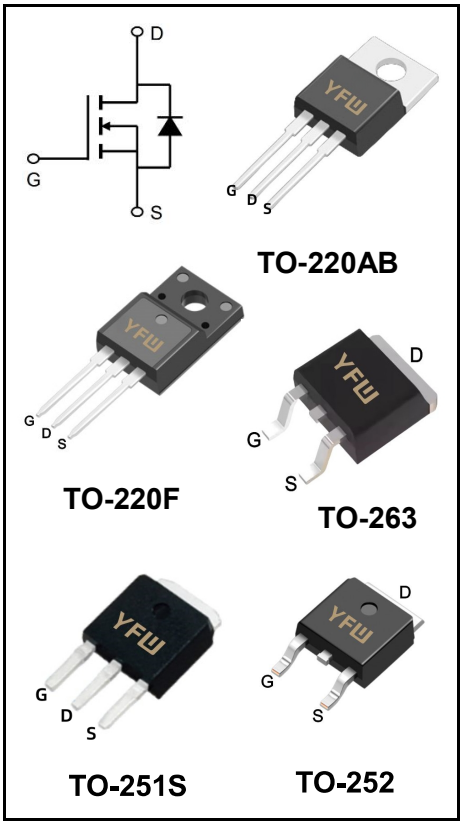
650V N-Channel Enhancement Mode Power MOSFET

MAIN CHARACTERISTICS

I_D	8A
V_{DSS}	650V
R_{DSON}-typ(@V_{GS}=10V)	<1.35Ω(Type:1.1 Ω)



Features

- Fast Switching
- Low ON Resistance
- Low Gate Charge
- 100% Single Pulse avalanche energy Test

APPLICATIONS

- Power switch circuit of adaptor and charger.

MECHANICAL DATA

- Case: Molded plastic
- Mounting Position: Any
- Molded Plastic: UL Flammability Classification Rating 94V-0
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Solder bath temperature 275℃ maximum,10s per JESD 22-B106

Maximum Ratings at Tc=25°C unless otherwise specified

Characteristics	Symbol	Value			Unit
		220AB/263	220F	251/252	
Drain-Source Voltage	V_{DS}	650			V
Gate-Source Voltage	V_{GS}	±30			V
Continue Drain Current	I_D	8			A
Pulsed Drain Current (Note1)	I_{DM}	28			A
Power Dissipation	P_D	100	30	100	W
Single Pulse Avalanche Energy (Note1)	E_{AS}	350			mJ
Operating Temperature Range	T_J	150			°C
Storage Temperature Range	T_{STG}	-55 to +150			°C
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.25	3.57	1.25	°C/W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62.5	62.5	100	°C/W

Note1:Pulse test: 300 μs pulse width, 2 % duty cycle

Electrical Characteristics at Tc=25°C unless otherwise specified

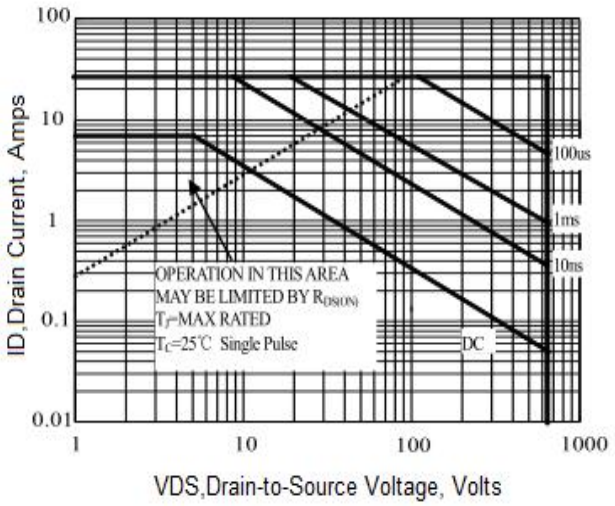
Characteristics	Test Condition	Symbol	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	V_{GS} = 0 V,I_D = 250 μA	BV_{DSS}	655	-	-	V
Drain-Source Leakage Current	V_{DS} = 655 V, V_{GS} = 0 V	I_{DSS}	-	-	1	μA
Gate Leakage Current	V_{GS} = ± 30 V, V_{DS} = 0 V	I_{GSS}	-	-	±100	nA
Gate-Source Threshold Voltage	V_{DS} = V_{GS} , I_D = 250 μA	$V_{GS(th)}$	2	-	4	V
Drain-Source On-State Resistance	V_{GS} = 10 V, I_D = 3.5 A	$R_{DS(on)}$	-	1.1	1.35	Ω
Forward Transconductance	V_{DS} = 15 V, I_D = 3.5 A	gfs	-	6.5	-	S
Input Capacitance	V_{GS} = 0 V, V_{DS} = 25 V, f = 1 MHz	C_{iss}	-	981	-	pF
Output Capacitance		C_{oss}	-	85	-	pF
Reverse Transfer Capacitance		C_{rss}	-	4	-	pF
Turn-on Delay Time(Note2)	I_D = 7 A, V_{DD} = 325 V, R_G= 10Ω	$t_{d(ON)}$	-	18	-	ns
Rise Time(Note2)		t_r	-	19	-	ns
Turn-Off Delay Time(Note2)		$t_{d(OFF)}$	-	39	-	ns
Fall Time(Note2)		t_f	-	18	-	ns
Total Gate Charge(Note2)	I_D = 7 A, V_{DD} = 520 V, V_{GS} = 10 V	Q_G	-	18	-	nC
Gate to Source Charge(Note2)		Q_{GS}	-	4.3	-	nC
Gate to Drain Charge(Note2)		Q_{GD}	-	7.6	-	nC

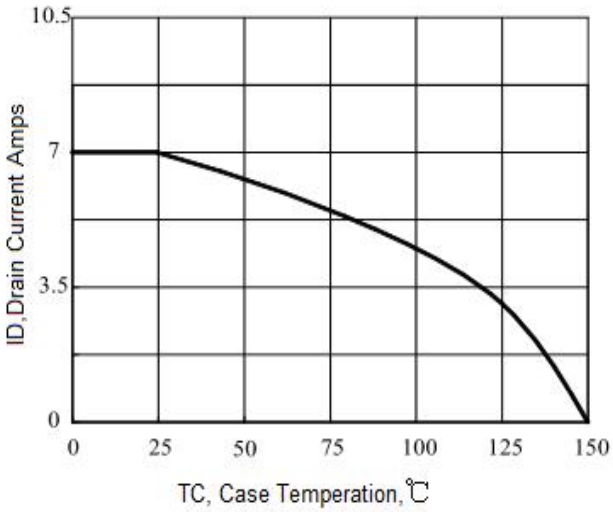
Source-Drain Diode Characteristics at Ta=25°C unless otherwise specified

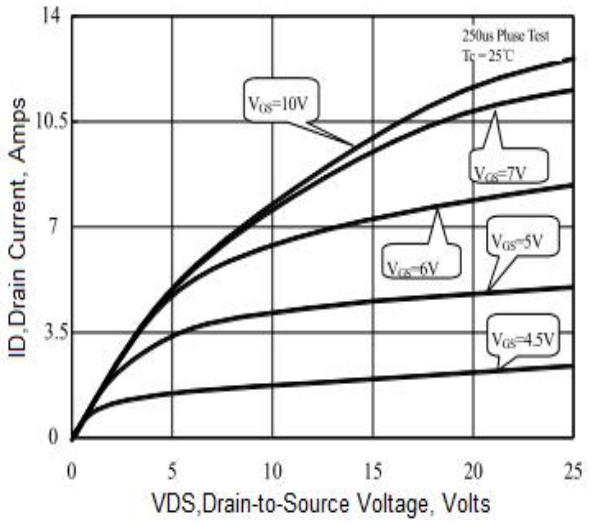
Characteristics	Test Condition	Symbol	Min.	Typ.	Max.	Unit
Maximun Body-Diode Continuous Current	Tj=25°C	I_S	-	-	8	A
Maximun Body-Diode Pulsed Current(Note2)		I_{SM}	-	-	28	A
Drain-Source Diode Forward Voltage	I_{SD} = 7 A	V_{SD}	-	-	1.4	V
Reverse Recovery Time(Note2)	I_{SD} = 7 A, V_{GS} = 0 V, dI_F / dt = 100 A/μs	trr	-	370	-	ns
Reverse Recovery Charge(Note2)		Qrr	-	1.9	-	μC

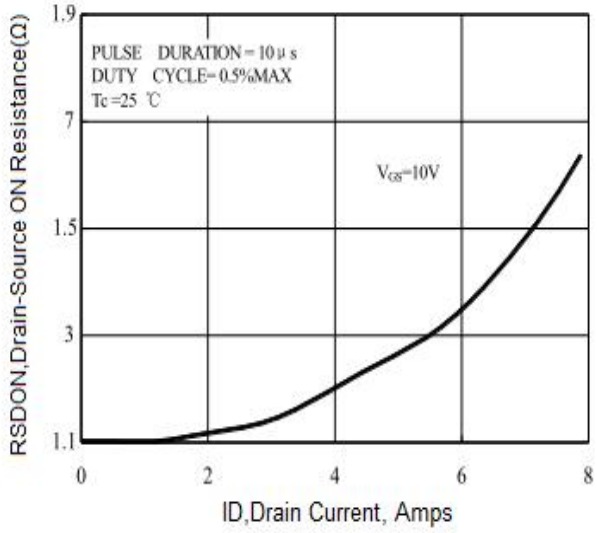
Note2:Pulse test: 300 μs pulse width, 2 % duty cycle

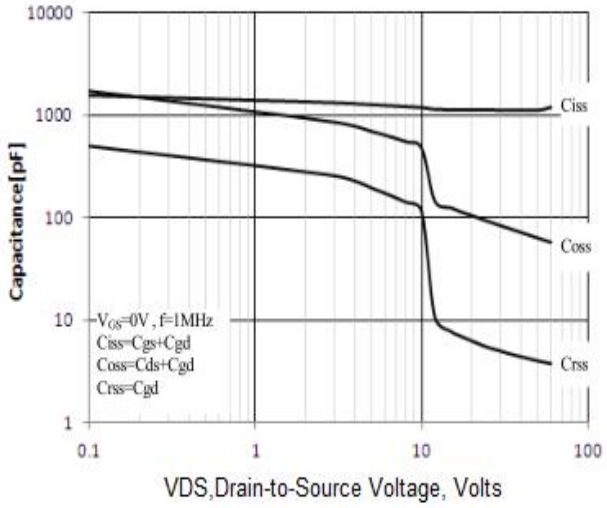
RATINGS AND CHARACTERISTIC CURVES

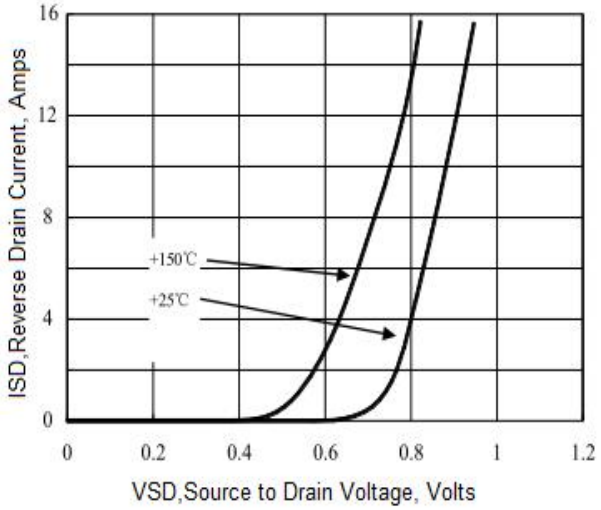




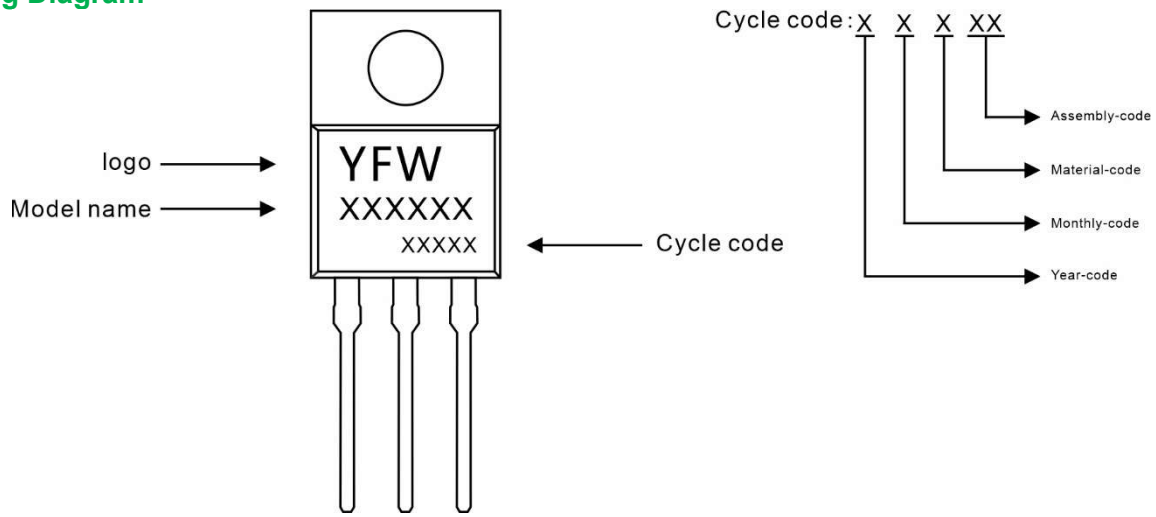








Marking Diagram

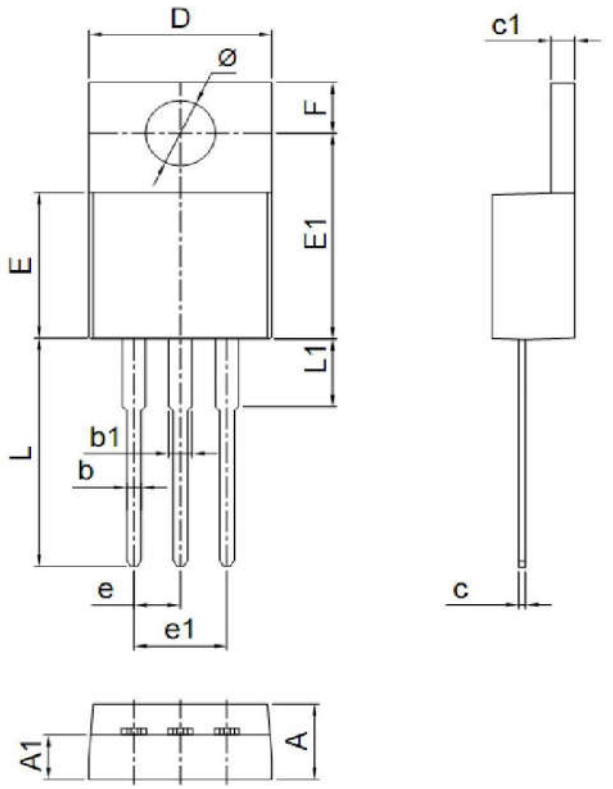


Ordering information

Model name	Package	Unit Weight	Base Quantity	Packing Quantity
YFW8N65AT	TO-220AB	0.07oz(1.96g)	50pcs/tube	1000PCS/Box 5000PCS/Carton

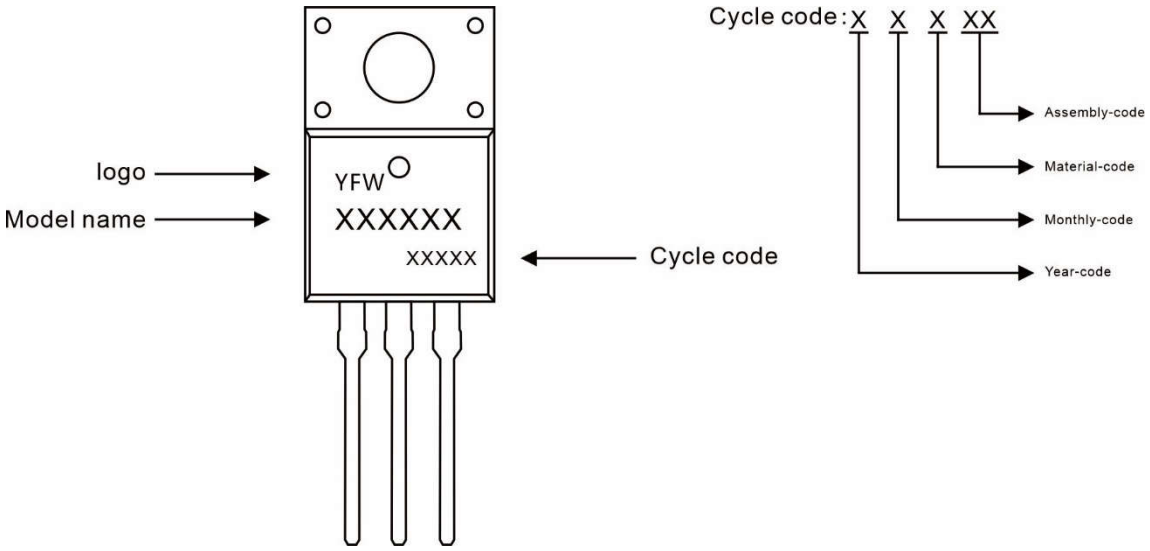
Package Dimensions

TO-220AB



Symbol	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.30	4.70	0.169	0.185
A1	2.52	2.82	0.099	0.111
b	0.71	0.91	0.028	0.036
b1	1.17	1.37	0.046	0.054
c	0.30	0.50	0.012	0.020
c1	1.17	1.37	0.046	0.054
D	9.90	10.20	0.390	0.402
E	8.50	8.90	0.335	0.350
E1	12.00	12.50	0.472	0.492
e	2.44	2.64	0.096	0.104
e1	4.88	5.28	0.192	0.208
F	2.60	2.80	0.102	0.110
L	13.20	13.80	0.520	0.543
L1	3.80	4.20	0.150	0.165
Φ	3.60	3.96	0.142	0.156

Marking Diagram

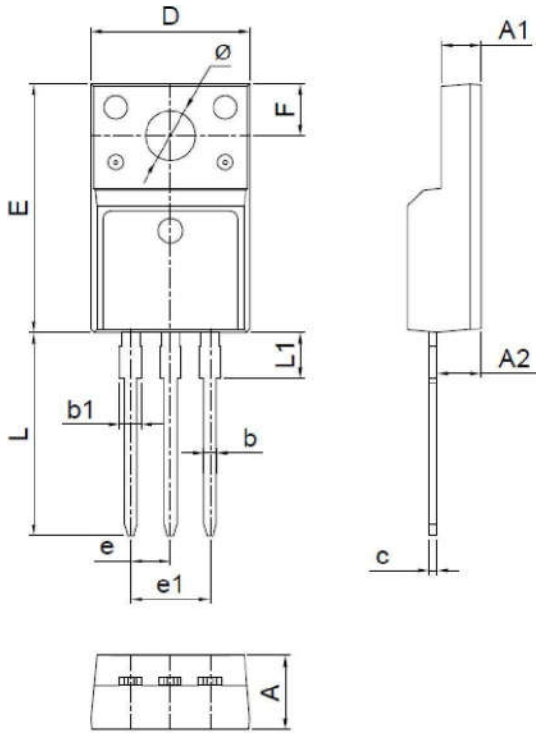


Ordering information

Model name	Package	Unit Weight	Base Quantity	Packing Quantity
YFW8N65AF	TO-220F	0.06oz(1.74g)	50pcs/tube	1000PCS/Box 5000PCS/Carton

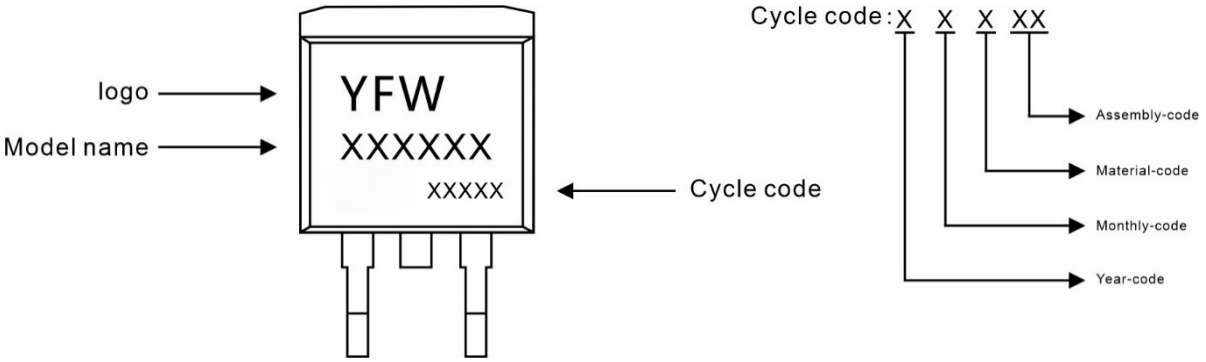
Package Dimensions

TO-220F



Symbol	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.50	4.90	0.177	0.193
A1	2.34	2.74	0.092	0.108
A2	2.66	2.86	0.105	0.113
b	0.75	0.85	0.030	0.033
b1	1.24	1.44	0.049	0.057
c	0.40	0.60	0.016	0.024
D	10.00	10.32	0.394	0.406
E	15.75	16.05	0.620	0.632
e	2.44	2.64	0.096	0.104
e1	4.88	5.28	0.192	0.208
F	3.10	3.5	0.122	0.138
L	13.50	13.90	0.531	0.547
L1	2.90	3.30	0.114	0.130
Φ	3.10	3.30	0.122	0.130

Marking Diagram

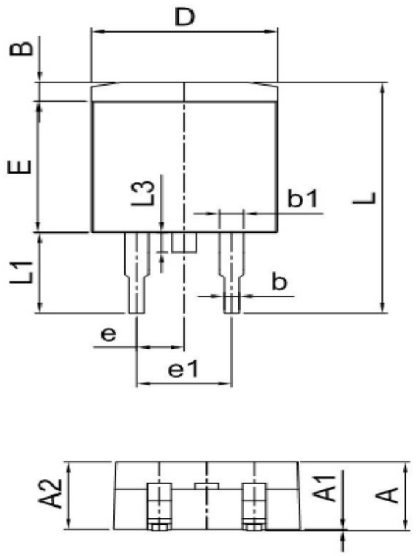


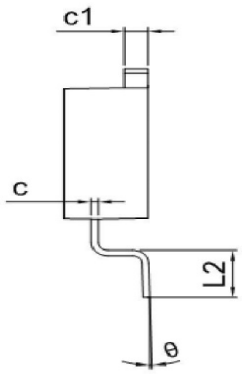
Ordering information

Model name	Package	Unit Weight	Base Quantity	Packing Quantity
YFW8N65AS	TO-263	0.04oz(1.16g)	800pcs/reel	1600pcs/box 8000pcs/Carton

Package Dimensions

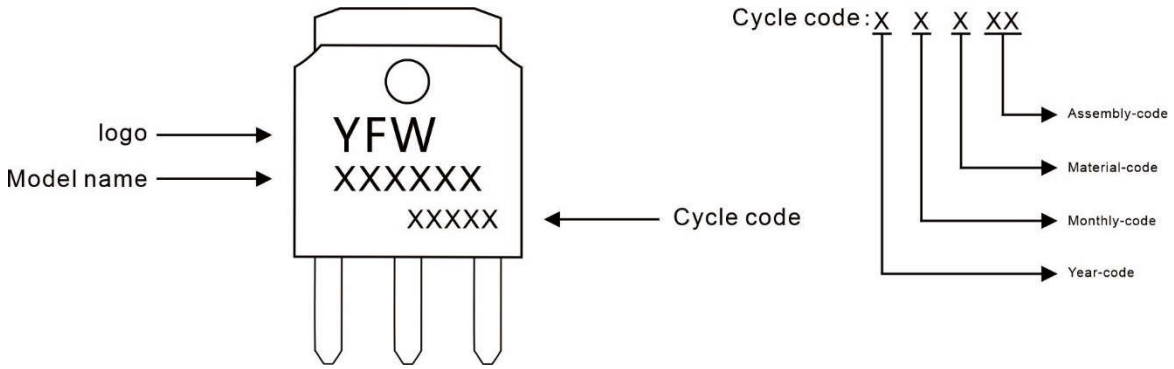
TO-263





Dim	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.30	4.70	0.169	0.185
A1	0.00	0.15	0.000	0.006
A2	4.30	4.55	0.169	0.179
B	1.10	1.50	0.043	0.059
b	0.70	0.90	0.028	0.035
b1	1.20	1.50	0.047	0.059
c	0.30	0.60	0.012	0.024
c1	1.17	1.37	0.046	0.054
D	9.90	10.20	0.390	0.402
E	8.50	8.90	0.335	0.350
e	2.44	2.64	0.096	0.104
e1	4.88	5.28	0.192	0.208
L	15.00	15.30	0.591	0.602
L1	5.20	5.40	0.205	0.213
L2	2.40	2.60	0.094	0.102
L3	1.60	1.80	0.063	0.071

Marking Diagram

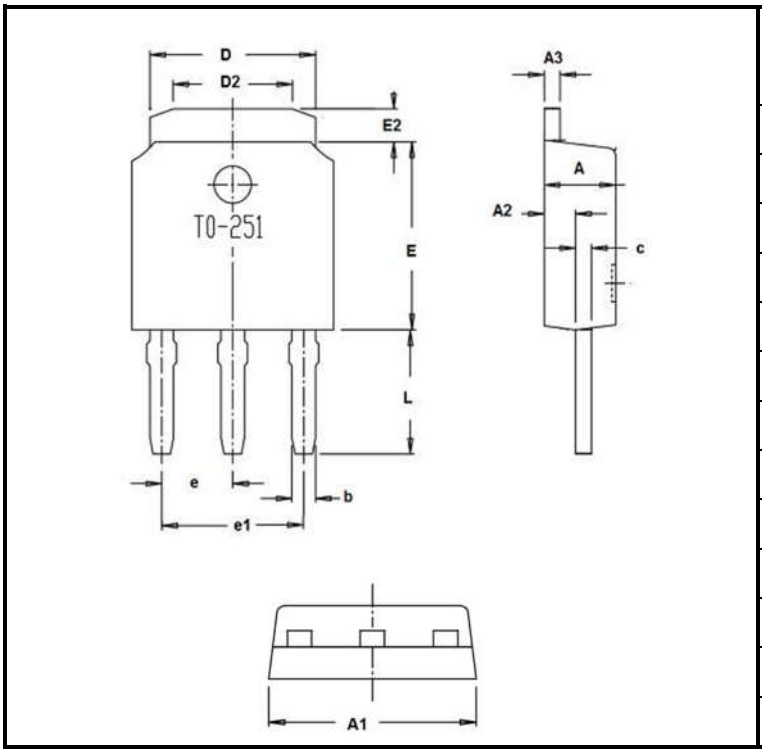


Ordering information

Model name	Package	Unit Weight	Base Quantity	Packing Quantity
YFW8N65AMJ	TO-251S	0.011oz(0.32g)	80pcs/tube	4000pcs/box 24000pcs/Carton

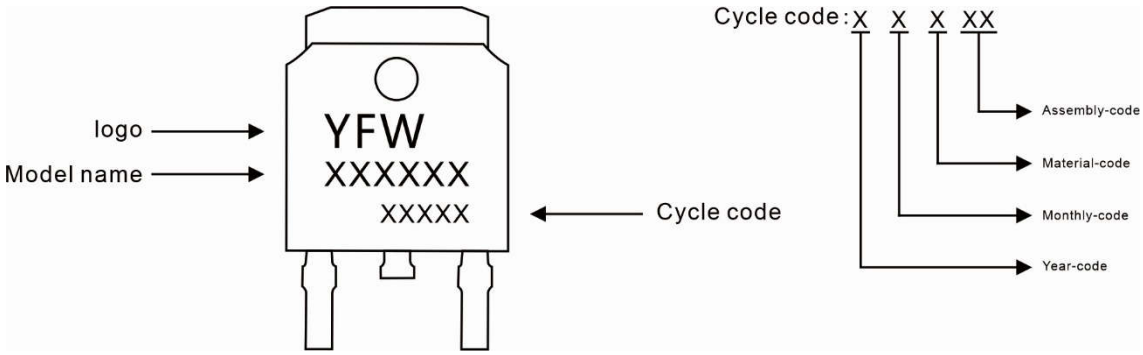
Package Dimensions

TO-251S



Dim	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	2.1	2.5	0.083	0.098
A1	6.3	6.9	0.248	0.271
A2	0.9	1.1	0.035	0.043
A3	TYP0.5		TYP0.019	
b	0.6	0.8	0.024	0.031
c	0.4	0.5	0.015	0.020
D	5.3	5.5	0.209	0.217
D2	3.65	4.05	0.144	0.159
E	5.8	6.4	0.228	0.252
E2	0.9	1.4	0.035	0.055
e	TYP2.29		TYP0.090	
e1	TYP4.58		TYP0.180	
L	3.7	4.3	0.146	0.169

Marking Diagram

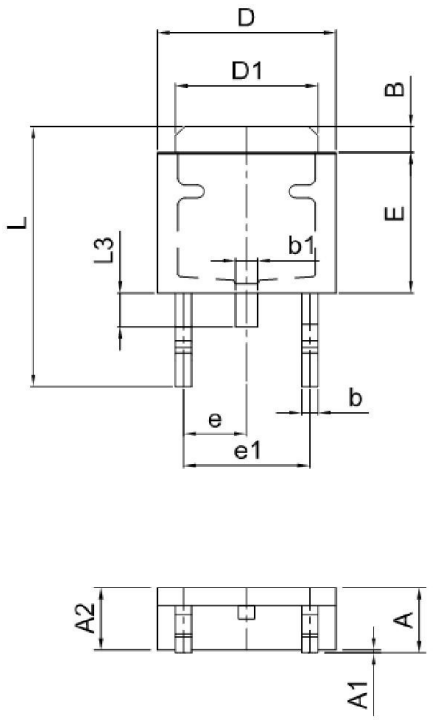


Ordering information

Model name	Package	Unit Weight	Base Quantity	Packing Quantity
YFW8N65AD	TO-252	0.011oz(0.32g)	2500pcs/reel	5000pcs/box 25000pcs/Carton

Package Dimensions

TO-252



Dim	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	2.20	2.50	0.087	0.098
A1	0.00	0.12	0.000	0.005
A2	2.20	2.40	0.087	0.094
B	1.20	1.60	0.047	0.063
b	0.50	0.70	0.020	0.028
b1	0.70	0.90	0.028	0.035
c	0.40	0.60	0.016	0.024
c1	0.40	0.60	0.016	0.024
D	6.35	6.65	0.250	0.262
D1	5.20	5.40	0.205	0.213
E	5.40	5.70	0.213	0.224
e	2.20	2.40	0.087	0.094
e1	4.40	4.80	0.173	0.189
L	10.00	11.00	0.393	0.433
L1	2.70	3.10	0.106	0.122
L2	1.40	1.80	0.055	0.071
L3	0.90	1.50	0.035	0.059

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